NSN 5962-01-169-5321

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-169-5321 **Body Length:** Between 1.230 inches and 1.270 inches **Body Width:** Between 0.510 inches and 0.530 inches **Body Height:** Between 0.125 inches and 0.190 inches **Operating Tempurature Range:** -55.0/+100.0 degrees celsius **Storage Tempurature Range:** -65.0/+125.0 degrees celsius **End Application:** Communication system an/msq-115 **Features Provided:** Hermetically sealed and electrostatic sensitive and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 28.0 volts power source

Time Rating Per Chacteristic:

450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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